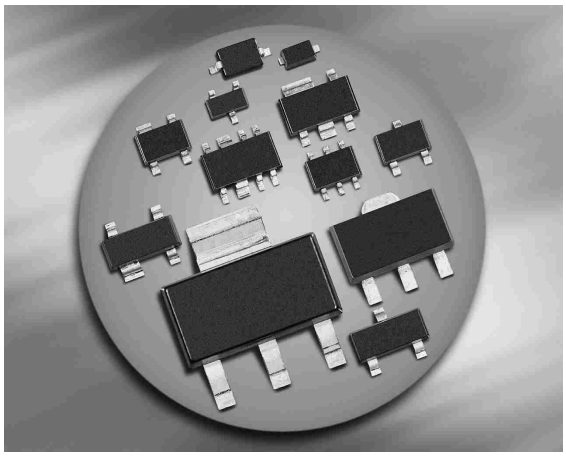
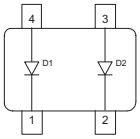
Silicon Switching Diode

- For high-speed switching applications
- Electrical insulated diodes



BAS28/W



Type	Package	Configuration	Marking
BAS28	SOT143	parallel pair	JTs
BAS28W	SOT343	parallel pair	JTs

Maximum Ratings at T_A = 25°C, unless otherwise specified

Parameter	Symbol	Value	Unit
Diode reverse voltage	V_R	80	V
Peak reverse voltage	V_{RM}	85	
Forward current	I_F	200	mA
Surge forward current, t = 1 µs	I_{FS}	4.5	A
Total power dissipation BAS28, $T_S \leq$ 31°C BAS28W, $T_S \leq$ 103°C	P_{tot}	 330 250	mW
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	-55 ... 150	

Thermal Resistance

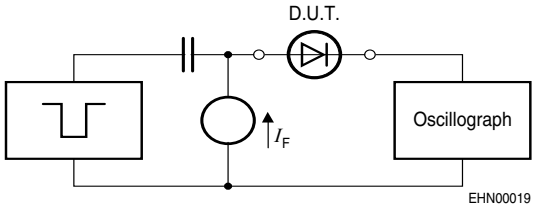
Parameter	Symbol	Value	Unit
Junction - soldering point[1)] BAS28 BAS28W	R_{thJS}	 ≤ 360 ≤ 190	K/W

[1]For calculation of R_{thJA} please refer to Application Note Thermal Resistance

Electrical Characteristics at T_A = 25°C, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics					
Breakdown voltage $I_{(BR)}$ = 100 µA	$V_{(BR)}$	85	-	-	V
Reverse current	I_R				µA
V_R = 75 V		-	-	0.1	
V_R = 25 V, T_A = 150 °C		-	-	30	
V_R = 75 V, T_A = 150 °C		-	-	50	
Forward voltage	V_F				mV
I_F = 1 mA		-	-	715	
I_F = 10 mA		-	-	855	
I_F = 50 mA		-	-	1000	
I_F = 100 mA		-	-	1200	
I_F = 150 mA		-	-	1250	
AC Characteristics					
Diode capacitance V_R = 0 V, f = 1 MHz	C_T	-	-	2	pF
Reverse recovery time I_F = 10 mA, I_R = 10 mA, measured at I_R = 1mA , R_L = 100 Ω	t_{rr}	-	-	4	ns

Test circuit for reverse recovery time

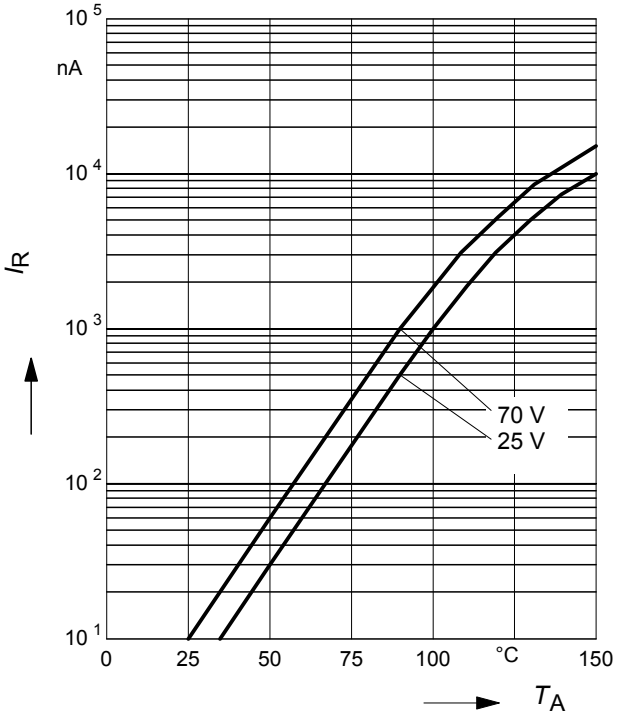


Pulse generator: t_p = 100ns, D = 0.05,
t_r = 0.6ns, R_i = 50Ω

Oscillograph: R = 50Ω, t_r = 0.35ns,
$C \leq$ 1pF

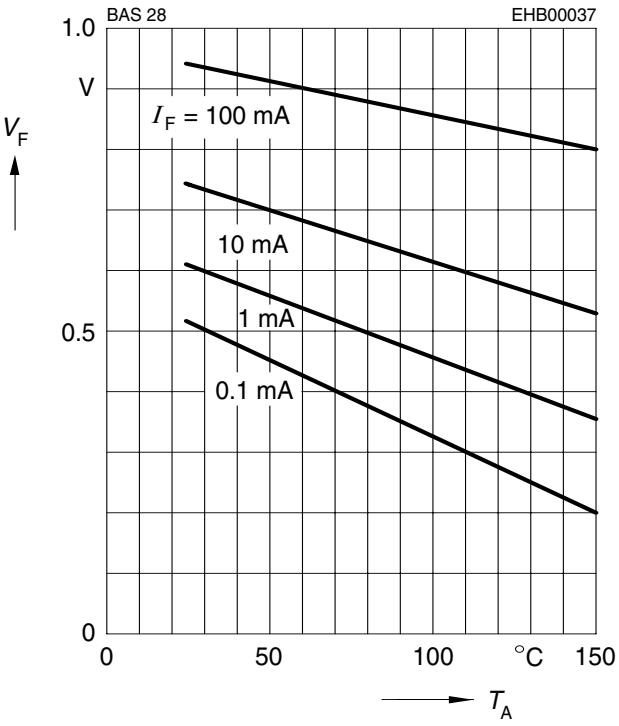
Reverse current $I_R = f\ (T_A)$

V_R = Parameter



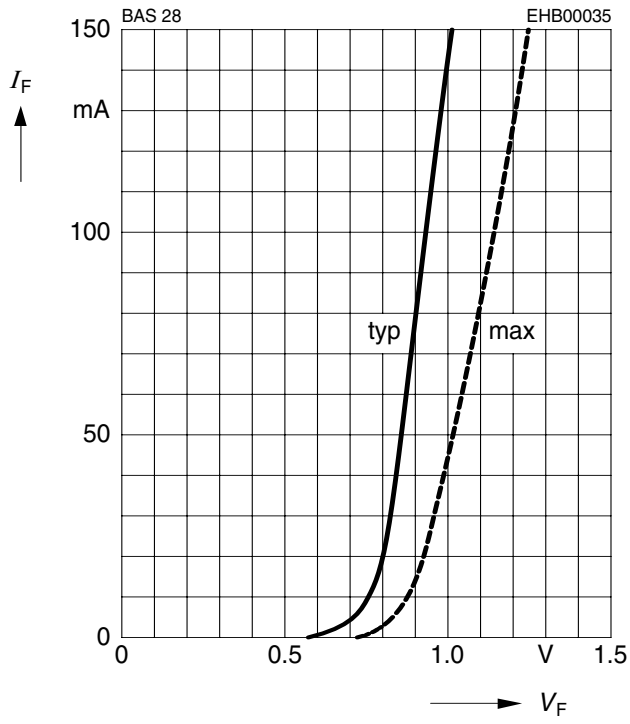
Forward Voltage $V_F = f\ (T_A)$

I_F = Parameter



Forward current $I_F = f\ (V_F)$

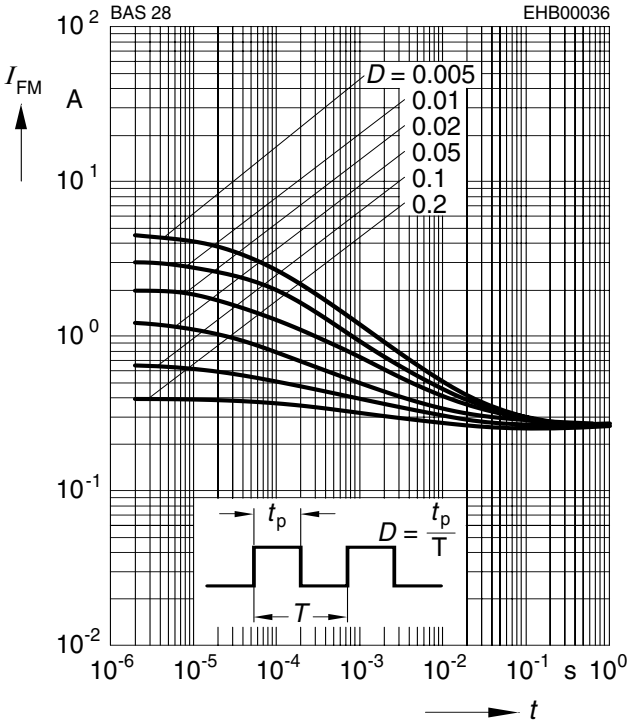
T_A = 25 °C



Peak forward current $I_{FM} = f\ (t_p)$

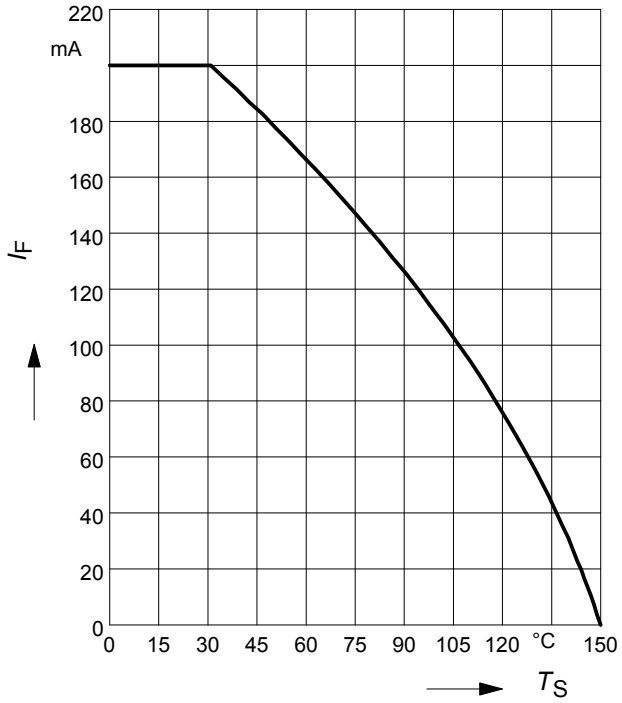
T_A = 25 °C

BAS28



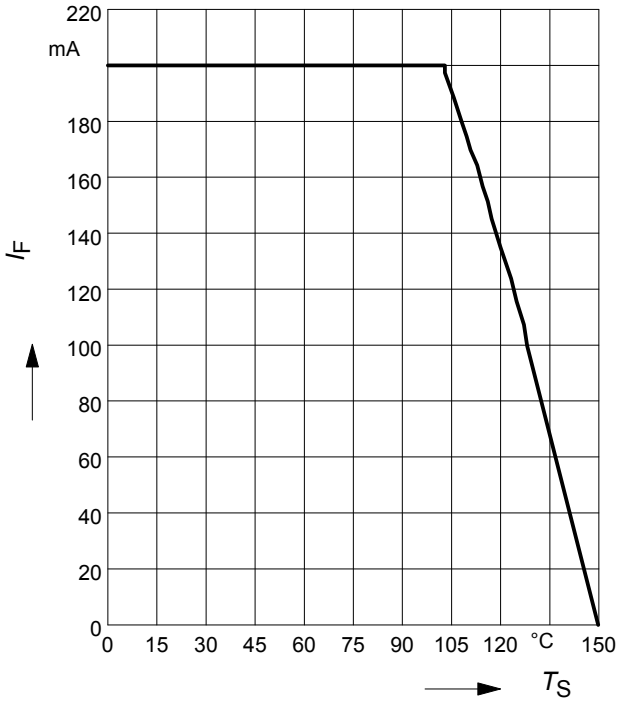
Forward current $I_F = f(T_S)$

BAS28



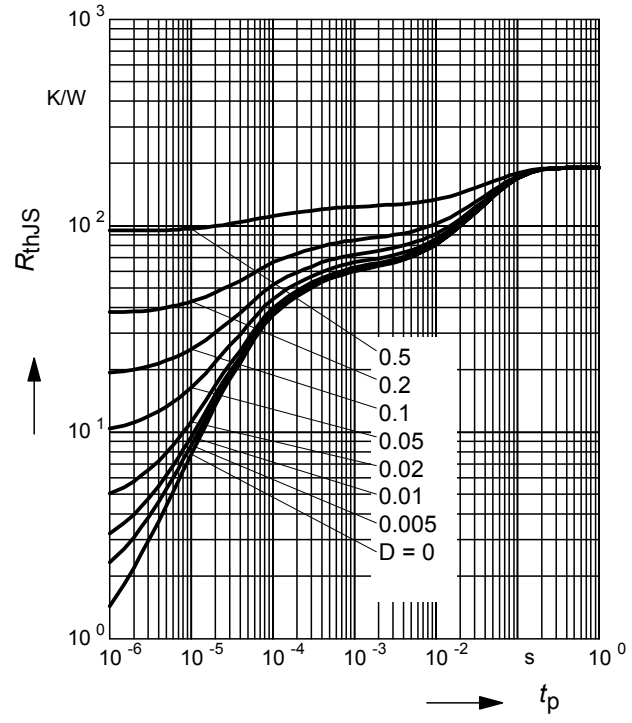
Forward current $I_F = f(T_S)$

BAS28W



Permissible Puls Load $R_{thJS} = f(t_p)$

BAS28W



Permissible Pulse Load

$I_{Fmax}/ I_{FDC} = f(t_p)$ BAS28W

